

Phase Control SCR 620 Amperes Average 600 Volts





Ordering Information:

Select the complete nine digit part number you desire from the table, i.e. C390MX500 is a 600 Volt, 620 Ampere Phase Control SCR.

	Voltage		Current
Туре	V _{DRM} V _{RRM} Cod		e I _{T(av)}
C390X500	200	в	620
	400	D	
	600	М	



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Description:

Powerex Silicon Controlled Rectifiers (SCR) are designed for phase control applications. These are all-diffused, Press-Pak (Pow-R-Disc) devices employing the field-proven amplifying (di/namic) gate.

Features:

- Low On-State Voltage
- High di/dt
- High dv/dt
- Hermetic Packaging
- Excellent Surge and I²t Ratings

Applications:

	Power	Supp	lies
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- Battery Chargers
- Motor Control



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Absolute Maximum Ratings

	Symbol	C390X500	Units
RMS On-State Current @ T _C = 65°C	I _{T(RMS)}	975	Amperes
Average On-State Current @ T _C = 65°C	I _{T(av)}	620	Amperes
Peak One-Cycle Surge (Non Repetitive) On-State Current (60Hz)	I _{TSM}	10,000	Amperes
Peak One-Cycle Surge (Non-Repetitive) On-State Current (50Hz)	I _{TSM}	9500	Amperes
Critical Rate-of-Rise of On-State Current (Non-Repetitive)	di/dt	400	Amperes/µs
Critical Rate-of-Rise of On-State Current (Repetitive)	di/dt	150	Amperes/µs
I ² t (for Fusing), One Cycle at 60Hz	l²t	416,500	A ² sec
Peak Gate Power Dissipation, 40 µsec Pulse	P _{GM}	200	Watts
Average Gate Power Dissipation	P _{G(av)}	5	Watts
Storage Temperature	T _{STG}	-40 to 150	•C
Operating Temperature	Tj	-40 to 125	° C
Mounting Force		1800 to 2200	lb.
Mounting Force		8 to 9.8	kN

Electrical and Thermal Characteristics

Characteristics	Symbol	Test Conditions	C390X500	Units
Voltage—Blocking State Maximums			·	
Forward Leakage, Peak	I _{DRM}	$T_{J} = 125^{\circ}C, V = V_{DRM}$	50	mA
Reverse Leakage, Peak	IRRM	$T_J = 125^{\circ}C, V = V_{RRM}$	50	mA
Current—Conducting State Maximums				
Peak On-State Voltage	V _{TM}	$I_{TM} = 3000A; T_J = 25^{\circ}C$	1.9	Volts
Switching Typical Turn-Off Time	t _q	$\begin{array}{l} T_{\rm J}=125^{\circ} C, \ I_{TM}=500 \ \text{Amps}; \ V_{\rm R}=50 \ \text{Volts Min.}; \\ V_{\rm DRM} \ (\text{Reapplied}); \ \text{Rate-of-Rise of Reapplied Off-} \\ \text{State Voltage}=20 V/\mu \text{sec (linear)}; \\ \text{Commutation di/dt}=25 A/\mu \text{sec;} \\ \text{Repetition Rate}=1 \ \text{pps; Gate Bias During} \\ \text{Turn-Off Interval}=0 \ \text{Volts, } 100 \Omega \end{array}$	125	μsec
Typical Delay Time	t _a	$T_J = 25^{\circ}C$, $I_{TM} = 50$ Adc, V_{DRM} Rated. Gate Supply: 20 Volts, 20 Ω , 0.1 μ sec Max. Rise Time	0.7	μsec
Min. Critical dv/dt exponential to VDRM	dv/dt	$T_{J} = 125^{\circ}C$, Gate Open	200	V/µsec
Thermal Maximum Thermal Resistance, double sided cooling Junction to Case	R _{evc}		0.06	°C/Watt
Case to Sink, Lubricated	R _{ecs}		0.02	°C/Watt
Gate—Maximum Parameters				
Gate Current to Trigger	I _{GT}	$V_D = 6Vdc$, $T_J = 25^{\circ}C$, $R_L = 3\Omega$	200	mA
Gate Voltage to Trigger	V _{GT}	$T_J = -40^{\circ}C$ to 125°C, $V_D = Vdc$, $R_L = 3\Omega$	5	Volts
Non-Triggering Gate Voltage		$T_J = 125^{\circ}C$, rated V_{DRM} , $R_L = 1000\Omega$	0.15	Volts
Peak Forward Gate Current	GTM		10	Amperes
Peak Reverse Gate Voltage	V _{GRM}		5	Volts



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FRANSIENT THERMAL IMPEDANCE, Zucon, ("C/WATT) 0. ШІ Π 111 00 Ш 11 HIII 0.00 Ш тнин Ш 0.0001 0.001 0.0 0.1 ю t TIME, t, (SECONDS)

TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (JUNCTION TO CASE)





AVERAGE ON-STATE CURRENT, IT(av), (AMPERES)

MAXIMUM ON-STATE POWER DISSIPATION (RECTANGULAR WAVEFORM)



AVERAGE ON-STATE CURRENT, IT(av), (AMPERES)



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MAXIMUM ALLOWABLE CASE TEMPERATURE (RECTANGULAR WAVEFORM) MAXIMUM ALLOWABLE CASE TEMPERATURE, Tc, (°C) 130 Single Side Co 50 - 400Hz 120 110 % Duty Cycle = 100 90 80 8.3 DC % Duty Cycle 70 16.7 33.3 50 60 0 100 200 300 400 500 AVERAGE ON-STATE CURRENT, IT(av), (AMPERES)



GATE CHARACTERISTICS

